



## SAM<sup>TM</sup> Data Sheet SAM-1064-10-1ps-x, $\lambda$ = 1064 nm

 $\lambda = 1064$  nm Laser wavelength

High reflection band  $\lambda$  = 1010 .. 1100 nm

Absorbance  $A_0 = 10 \%$  $\Delta R = 6 \%$ Modulation depth Non-saturable loss  $A_{ns} = 4 \%$ 

Saturation fluence  $\Phi_{\text{sat}} = 35 \,\mu\text{J/cm}^2$ 

Relaxation time constant  $\tau \sim 1 \text{ ps}$ 

 $\Phi$  = 2.5 mJ/cm<sup>2</sup> Damage threshold

4.0 mm x 4.0 mm; other dimensions on request Chip area

Chip thickness 450 µm

Protection the SAM is protected with a dielectric front layer

Mounting option **x** denotes the type of mounting as follows:

unmounted  $\mathbf{x} = 0$ 

x = 12.7 gglued on a copper heat sink with 12.7 mm  $\varnothing$ x = 25.4 gglued on a copper heat sink with 25.4 mm Ø x = 12.7 ssoldered on a copper heat sink with 12.7 mm  $\varnothing$ x = 25.4 ssoldered on a copper heat sink with 25.4 mm Ø

x = 25.0 wsoldered on a water cooled copper heat sink with 25.0 mm Ø x = FCmounted on a 1 m single mode fiber with FC connector

## Low intensity spectral reflectance

